



## Silicon Controlled Rectifiers

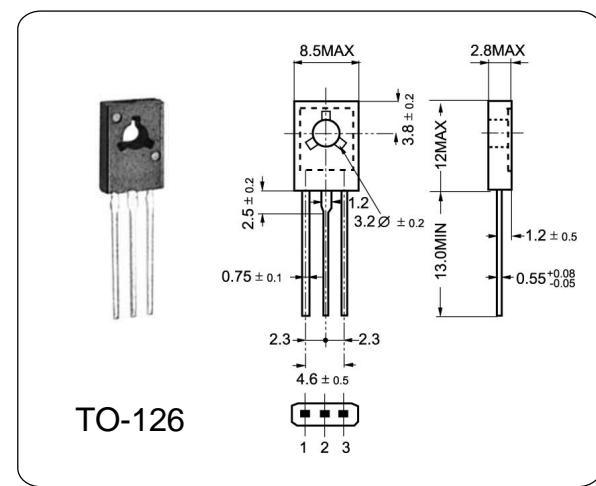
SCR6C60

## DESCRIPTION

Standard gate triggering SCR is suitable for the application where requiring high bidirectional blocking voltage capability and also suitable for over voltage protection ,motor control circuit in power tool, inrush current limit circuit and heating control system.

## ABSOLUTE MAXIMUM RATINGS ( Ta = 25 °C)

Parameter	Symbol	Typ	Unit
Repetitive peak off-state voltages	$V_{DRM}$ $V_{RRM}$	600	V
Average on-state current	$I_{T(AV)}$	3.8	A
RMS on-state current	$I_{T(RMS)}$	6.0	A
Non-repetitive peak on-state current	$I_{TSM}$	66	A
Max. Operating Junction Temperature	$T_j$	110	°C
Storage Temperature	$T_{stg}$	-45~150	°C



## ELECTRICAL CHARACTERISTICS ( Ta = 25 °C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Repetitive peak off-state voltages	$V_{DRM}$ $V_{RRM}$		600	—	—	V
Average on-state current	$I_{T(AV)}$	half sine wave; $T_{mb} < 103$ °C	—	3.8	—	A
RMS on-state current	$I_{T(RMS)}$	all conduction angles	—	6.0	—	A
On-state voltage	$V_{TM}$	$I_{TM}=9.0$ A, $t_p=380$ µ s	—	—	1.6	V
Holding current	$I_H$	$V_D = 12$ V; $I_{GT} = 0.1$ A	—	—	20	mA
Latching current	$I_L$	$V_D = 12$ V; $I_{GT} = 0.1$ A	—	—	50	mA
Gate trigger current	$I_{GT}$	$V_D = 12$ V; $I_T = 0.1$ A	—	4	15	mA
Gate trigger voltage	$V_{GT}$	$V_D = 12$ V; $I_T = 0.1$ A	—	0.6	1.5	V